



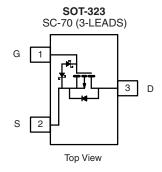
P-Channel 1.8 V (G-S) MOSFET

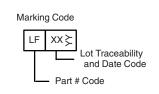
PRODUCT SUMMARY					
V _{DS} (V)	$R_{DS(on)}\left(\Omega\right)$	I _D (A)			
	0.290 at V _{GS} = - 4.5 V	± 0.91			
- 12	0.435 at V _{GS} = - 2.5 V	± 0.74			
	0.580 at V _{GS} = - 1.8 V	± 0.64			

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- ESD Protection: 3000 V
- Compliant to RoHS Directive 2002/95/EC







Ordering Information: Si1307EDL-T1-E3 (Lead (Pb)-free)

Si1307EDL-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATING	i S T _A = 25 °C, ur	nless otherwis	se noted			
Parameter		Symbol	5 s	Steady State	Unit	
Drain-Source Voltage		V _{DS}	- 12		V	
Gate-Source Voltage		V _{GS}	± 8			
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 25 °C	- I _D	± 0.91	± 0.85		
	T _A = 70 °C		± 0.72	± 0.68		
Pulsed Drain Current		I _{DM}	± 3		Α	
Continuous Diode Current (Diode Conduction) ^a		I _S	- 0.28	- 0.24		
Maximum Power Dissipation ^a	T _A = 25 °C	Б	0.34	0.29	W	
	T _A = 70 °C	P _D	0.22	0.19		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150		°C	

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^a	t ≤ 5 s	- R _{thJA}	315	375	°C/W
Maximum Junction-to-Ambient	Steady State		360	430	
Maximum Junction-to-Foot (Drain)	Steady State	R _{thJF}	285	340	

Notes:

a. Surface mounted on 1" x 1" FR4 board.

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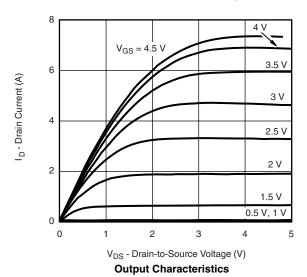
SPECIFICATIONS T _J = 25 °C, unless otherwise noted							
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	- 0.45			V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 4.5 \text{ V}$			± 1		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = - 9.6 V, V _{GS} = 0 V			- 1	μΑ	
		V _{DS} = - 9.6 V, V _{GS} = 0 V, T _J = 70 °C			- 5		
On-State Drain Current ^a	I _{D(on)}	V _{DS} - 5 V, V _{GS} = - 4.5 V	- 3			Α	
Drain-Source On-State Resistance ^a	R _{DS(on)}	V _{GS} = - 4.5 V, I _D = - 1 A		0.240	0.290		
		V _{GS} = - 2.5 V, I _D = - 0.5 A		0.350	0.435	Ω	
		V _{GS} = - 1.8 V, I _D = - 0.3 A		0.480	0.580		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 5 V, I _D = - 1 A		3.5		S	
Diode Forward Voltage ^a	V_{SD}	I _S = - 1 A, V _{GS} = 0 V			- 1.2	V	
Dynamic ^b							
Total Gate Charge	Qg			3.2	5		
Gate-Source Charge	Q _{gs}	$V_{DS} = -6 \text{ V}, V_{GS} = -4.5 \text{ V}, I_D = -1 \text{ A}$		0.69		nC	
Gate-Drain Charge	Q_{gd}			0.61			
Turn-On Delay Time	t _{d(on)}			210	340		
Rise Time	t _r	$V_{DD} = -6 \text{ V}, R_L = 6 \Omega$		450	720	ns	
Turn-Off Delay Time	t _{d(off)}	$I_D \cong -1 \text{ A, } V_{GEN} = -4.5 \text{ V, } R_g = 6 \Omega$		910	1550		
Fall Time	t _f			1000	1600		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = - 1 A, dI/dt = 100 A/μs		540	860		

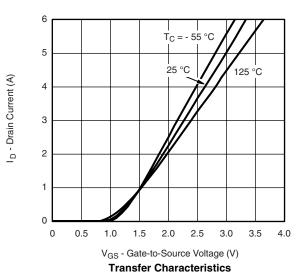
Notes:

- a. Pulse test; pulse width $\leq 300~\mu s,$ duty cycle $\leq 2~\%.$
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



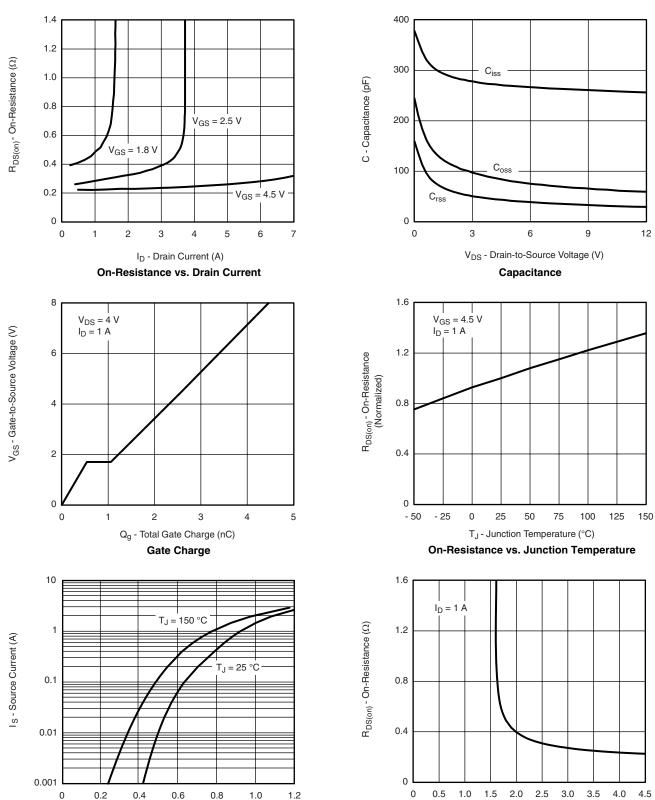








TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



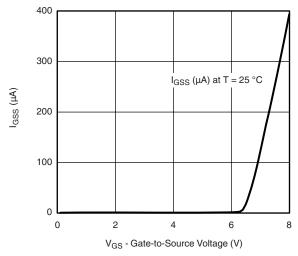
 V_{SD} - Source-to-Drain Voltage (V) **Source-Drain Diode Forward Voltage** V_{GS} - Gate-to-Source Voltage (V)

On-Resistance vs. Gate-Source Voltage

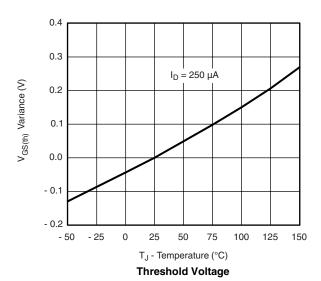
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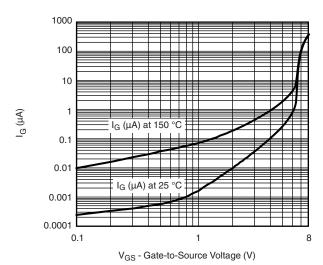
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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

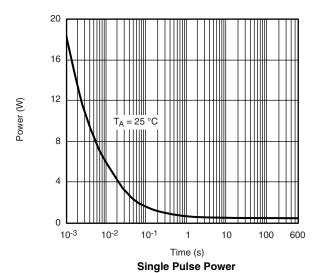


Gate-Current vs. Gate-to-Source Voltage



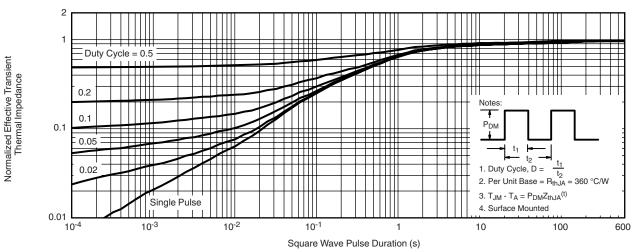


Gate-to-Source Voltage vs. Gate Current

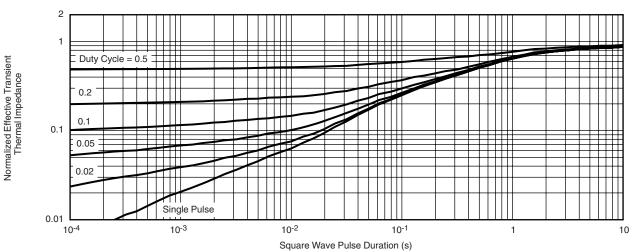




TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Ambient



Normalized Thermal Transient Impedance, Junction-to-Foot

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